

Ultra Low Current Low Noise Amplifier for L2/L5 GNSS Applications

Features

• Operation frequencies: 1164 to 1300 MHz

• Ultra low current consumption: 1.3 mA

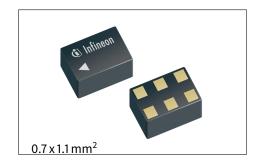
• Wide supply voltage range: 1.1 V to 3.3 V

• High insertion power gain: 20.0 dB

• Low noise figure: 0.80 dB

• 2 kV HBM ESD protection (inluding AI pin)

• Ultra small and RoHS/WEEE compliant package



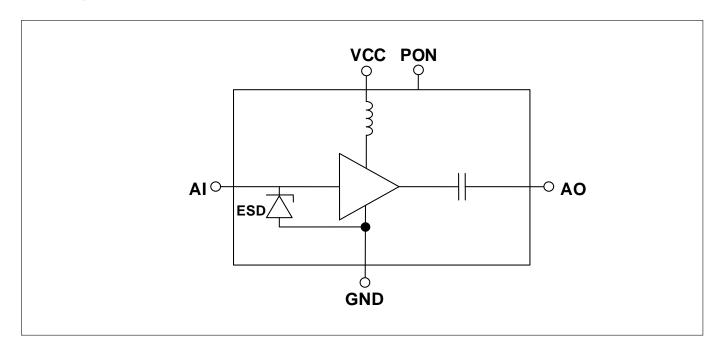
Potential Application

The BGA125N6 is designed to enhance GNSS signal sensitivity for band L2/L5 especially in wearables and mobile cellular IoT applications. With the very good performance it ensures high system sensitivity. The ultra low power consumption of 1.5mW preserves valuable battery power, ideal for small battery powered GNSS devices. The wide supply voltage range from 1.1 V to 3.3 V ensure flexible design and high compatibility. Besides GPS L2 and L5, the GNSS LNA also covers Galileo E5a, E5b, E6, Glonass G3, G2, Beidou B3, B2 and IRNSS/NAVIC bands.

Product Validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Block diagram



Ultra Low Current Low Noise Amplifier for L2/L5 GNSS Applications



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1

Ultra Low Current Low Noise Amplifier for L2/L5 GNSS Applications



Features

1 Features

Operation frequencies: 1164 to 1300 MHz
Ultra low current consumption: 1.3 mA

• Wide supply voltage range: 1.1 V to 3.3 V

• High insertion power gain: 20.0 dB

• Low noise figure: 0.80 dB

• 2 kV HBM ESD protection (inluding AI pin)

• Only one external matching component needed

• Ultra small TSNP-6-2 leadless package (footprint: 0.7 x 1.1 mm²)

• RoHS/WEEE compliant package





Description

The BGA125N6 is designed to enhance GNSS signal sensitivity for band L2/L5 especially in wearables and mobile cellular IoT applications. With the very good performance it ensures high system sensitivity. The ultra low power consumption of 1.5mW preserves valuable battery power, ideal for small battery powered GNSS devices. The wide supply voltage range from 1.1 V to 3.3 V ensure flexible design and high compatibility. Besides GPS L2 and L5, the GNSS LNA also covers Galileo E5a, E5b, E6, Glonass G3, G2, Beidou B3, B2 and IRNSS/NAVIC bands. The BGA125N6 LNA is manufactured in Infineon's patented bipolar technology.

The device has a very small size of only 0.7 x 1.1 mm² and a maximum height of 0.375 mm. The device configuration is shown in Fig. 1.

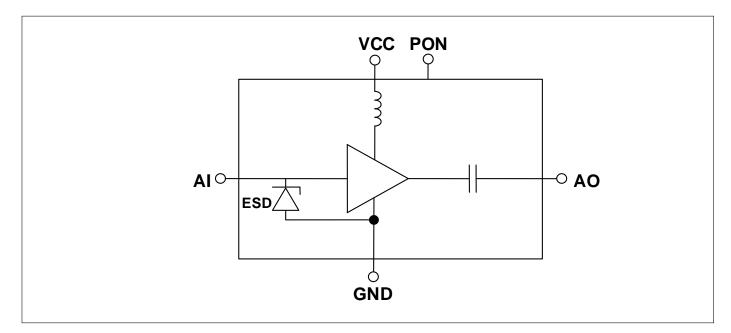


Figure 1: BGA125N6 Block diagram

| Product Name | Marking | Package |
|--------------|---------|-------------|
| BGA125N6 | 7 | PG-TSNP-6-2 |

Ultra Low Current Low Noise Amplifier for L2/L5 GNSS Applications



Maximum Ratings

2 Maximum Ratings

Table 1: Maximum Ratings

| Parameter | Symbol Values | | | | Unit | Note / Test Condition | |
|---------------------------|----------------------|-------|------|-----------------------|------|-----------------------|--|
| | | Min. | Тур. | Max. | | | |
| Voltage at pin VCC | V _{CC} | -0.3 | _ | 3.6 | ٧ | 1 | |
| Voltage at pin AI | V _{AI} | -0.3 | _ | 0.9 | ٧ | - | |
| Voltage at pin AO | V _{AO} | -0.3 | _ | V _{CC} + 0.3 | ٧ | - | |
| Voltage at pin PON | V _{PON} | -0.3 | _ | V _{CC} + 0.3 | ٧ | - | |
| Voltage at pin GND | V_{GND} | -0.3 | _ | 0.3 | ٧ | - | |
| Current into pin VCC | I _{cc} | _ | _ | 9 | mA | - | |
| RF input power | P _{IN} | _ | _ | +25 | dBm | 2 | |
| Total power dissipation | P _{tot} | _ | _ | 60 | mW | - | |
| Junction temperature | TJ | _ | _ | 150 | °C | - | |
| Ambient temperature range | T _A | -40 | _ | 85 | °C | - | |
| Storage temperature range | T_{STG} | -55 | _ | 150 | °C | _ | |
| ESD capability, HBM | V _{ESD_HBM} | -2000 | _ | +2000 | ٧ | 3 | |

¹All voltages refer to GND-Nodes unless otherwise noted

Warning: Stresses above the max. values listed here may cause permanent damage to the device. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit. Exposure to conditions at or belowabsolute maximum rating but above the specified maximum operation conditions may affect device reliability and life time. Functionality of the device might not be given under these conditions.

 $^{^2\}text{Tested}$ at max VCC/VPON, 85°C and for 60 minutes

 $^{^3}$ Human Body Model ANSI/ESDA/JEDEC JS-001 ($R=1.5~\mathrm{k}\Omega$, $C=100~\mathrm{pF}$)

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Electrical Characteristics

3 Electrical Characteristics

Table 3: Electrical Characteristics at T_A = 25 °C, V_{CC} = 1.2 V, f = 1164–1300 MHz

| Parameter ¹ | Symbol | Values | | | Unit | Note / Test Condition | |
|--|-----------------------------------|--------|------|-----------------|------|-----------------------|--|
| | | Min. | Тур. | Max. | | | |
| Supply Voltage | V _{cc} | 1.1 | 1.2 | 3.3 | V | _ | |
| C 1 - C 1 | , | _ | 1.3 | 1.65 | mA | ON-Mode | |
| Supply Current | I _{cc} | _ | 0.2 | 3 | μΑ | OFF-Mode | |
| Danier a Valta aa | 17 | 1.1 | _ | V _{cc} | V | ON-Mode | |
| Power on Voltage | V_{PON} | 0.0 | _ | 0.4 | V | OFF-Mode | |
| Davier on Current | , | _ | 1.5 | 3 | μΑ | ON-Mode | |
| Power on Current | I I _{PON} | _ | _ | 1 | μΑ | OFF-Mode | |
| Insertion Power Gain | $ S_{21} ^2$ | 17.6 | 19.6 | 21.6 | dB | ON-Mode | |
| f = 1176 MHz | | | | | | | |
| Noise Figure ² | NF | _ | 0.85 | 1.25 | dB | ON-Mode | |
| $f = 1176 \text{ MHz } Z_{S} = 50\Omega$ | | | | | | | |
| Input return loss ³ | RL _{IN} | 8.5 | 11 | _ | dB | ON-Mode | |
| f = 1176 MHz | | | | | | | |
| Output return loss ³ | RL _{OUT} | 10 | 15 | _ | dB | ON-Mode | |
| f = 1176 MHz | | | | | | | |
| Reverse isolation ³ | 1/ S ₂₁ ² | 25 | 40 | _ | dB | ON-Mode | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Power up settling time ^{4 5} | t _S | _ | 9 | 12 | μs | OFF- to ON-Mode | |
| Inband input 1dB-compression | IP _{1dB} | -21 | -17 | - | dBm | ON-Mode | |
| point ³ | | | | | | | |
| f = 1176 MHz | | | | | | | |
| Inband input 3rd-order intercept | IIP ₃ | -20 | -15 | _ | dBm | ON-Mode | |
| point ^{3 6} | | | | | | | |
| Out of band input 3rd-order in- | IIP _{300B} | -3 | 2 | _ | dBm | ON-Mode | |
| tercept point ^{5 7} | | | | | | | |
| Stability ⁵ | k | >1 | _ | _ | | f=20 MHz-10 GHz | |

¹Based on application described in chapter 4

²PCB losses are substrated

³Verification based on AQL; not 100% tested in production

⁴LNA gain changed to 90% of final gain value (in dB)

⁵Guaranteed by device design; not tested in production

⁶Inband @ 1176 MHz, Input power = -30 dBm for each tone, 1 MHz tone distance 7 f1 = 1785 MHz, f2 = 2401 MHz, Input power = -20 dBm for each tone

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Electrical Characteristics

Table 4: Electrical Characteristics at $T_{\rm A}$ = 25 °C, $V_{\rm CC}$ = 1.8 V, f = 1164–1300 MHz

| Parameter ¹ | Symbol | Values | | | Unit | Note / Test Condition | |
|--|-----------------------------------|--------|------|-----------------|------|-----------------------|--|
| | | Min. | Тур. | Max. | | | |
| Supply Voltage | V _{cc} | 1.1 | 1.8 | 3.3 | V | _ | |
| C. and C. and | , | _ | 1.35 | 1.7 | mA | ON-Mode | |
| Supply Current | I _{cc} | _ | 0.2 | 3 | μΑ | OFF-Mode | |
| D William | 17 | 1.1 | _ | V _{CC} | V | ON-Mode | |
| Power on Voltage | V_{PON} | 0.0 | _ | 0.4 | V | OFF-Mode | |
| D C | | _ | 1.5 | 3 | μΑ | ON-Mode | |
| Power on Current | I I _{PON} | _ | _ | 1 | μΑ | OFF-Mode | |
| Insertion Power Gain | $ S_{21} ^2$ | 18.0 | 20.0 | 22.0 | dB | ON-Mode | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Noise Figure ² | NF | - | 0.80 | 1.20 | dB | ON-Mode | |
| $f = 1176 \text{ MHz } Z_S = 50\Omega$ | | | | | | | |
| Input return loss ³ | RL _{IN} | 8.5 | 11 | _ | dB | ON-Mode | |
| f = 1176 MHz | | | | | | | |
| Output return loss ³ | RL _{OUT} | 10 | 14 | _ | dB | ON-Mode | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Reverse isolation ³ | 1/ S ₂₁ ² | 25 | 40 | _ | dB | ON-Mode | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Power up settling time ^{4 5} | t _S | _ | 8 | 11 | μs | OFF- to ON-Mode | |
| Inband input 1dB-compression | IP _{1dB} | -19 | -15 | _ | dBm | ON-Mode | |
| point ³ | | | | | | | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Inband input 3rd-order intercept | IIP ₃ | -20 | -15 | _ | dBm | ON-Mode | |
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| Stability ⁵ | k | >1 | _ | _ | | f=20 MHz-10 GHz | |

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Electrical Characteristics

Table 5: Electrical Characteristics at $T_{\rm A}$ = 25 °C, $V_{\rm CC}$ = 2.8 V, f = 1164–1300 MHz

| Parameter ¹ | Symbol | Values | | | Unit | Note / Test Condition | |
|--|-----------------------------------|--------|------|-----------------|------|-----------------------|--|
| | | Min. | Тур. | Max. | | | |
| Supply Voltage | V _{cc} | 1.1 | 2.8 | 3.3 | V | - | |
| Committee Committee | , | _ | 1.45 | 1.8 | mA | ON-Mode | |
| Supply Current | I _{cc} | _ | 0.2 | 3 | μΑ | OFF-Mode | |
| Danier Walter a | 17 | 1.1 | _ | V _{cc} | V | ON-Mode | |
| Power on Voltage | V_{PON} | 0.0 | _ | 0.4 | V | OFF-Mode | |
| Davier on Current | , | _ | 1.5 | 3 | μΑ | ON-Mode | |
| Power on Current | I I _{PON} | _ | - | 1 | μΑ | OFF-Mode | |
| Insertion Power Gain | $ S_{21} ^2$ | 18.7 | 20.2 | 22.2 | dB | ON-Mode | |
| f = 1176 MHz | | | | | | | |
| Noise Figure ² | NF | _ | 0.80 | 1.20 | dB | ON-Mode | |
| $f = 1176 \text{ MHz } Z_S = 50\Omega$ | | | | | | | |
| Input return loss ³ | RL _{IN} | 8.5 | 11 | - | dB | ON-Mode | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Output return loss³ | RL _{OUT} | 10 | 15 | - | dB | ON-Mode | |
| f = 1176 MHz | | | | | | | |
| Reverse isolation ³ | 1/ S ₂₁ ² | 25 | 40 | _ | dB | ON-Mode | |
| <i>f</i> = 1176 MHz | | | | | | | |
| Power up settling time ^{4 5} | t _S | _ | 8 | 11 | μs | OFF- to ON-Mode | |
| Inband input 1dB-compression | IP _{1dB} | -16 | -12 | _ | dBm | ON-Mode | |
| point ³ | | | | | | | |
| f = 1176 MHz | | | | | | | |
| Inband input 3rd-order intercept | IIP ₃ | -19 | -14 | - | dBm | ON-Mode | |
| point ^{3 6} | | | | | | | |
| Out of band input 3rd-order in- | IIP _{300B} | -3 | 2 | - | dBm | ON-Mode | |
| tercept point ^{5 7} | | | | | | | |
| Stability ⁵ | k | >1 | _ | - | | f=20 MHz-10 GHz | |

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Application Information

4 Application Information

Pin Configuration and Function

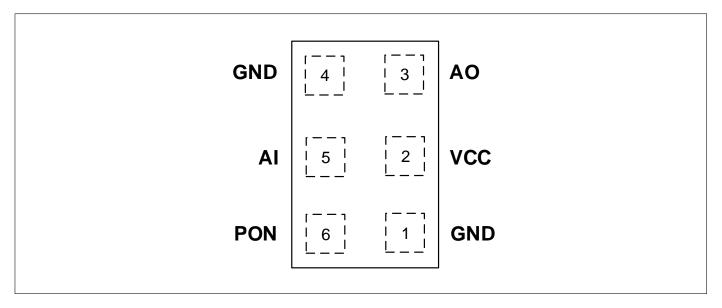


Figure 2: BGA125N6 Pin Configuration (top view)

Table 6: Pin Definition and Function

| Pin No. | Name | Function |
|---------|------|------------------|
| 1 | GND | Ground |
| 2 | VCC | DC Supply |
| 3 | AO | LNA Output |
| 4 | GND | Ground |
| 5 | Al | LNA Input |
| 6 | PON | Power On Control |





Application Information

Application Board Configuration

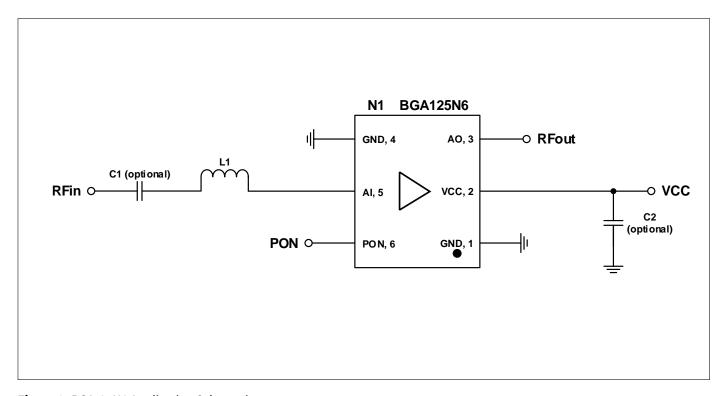


Figure 3: BGA125N6 Application Schematic

Table 7: Bill of Materials Table

| Name | Value | Package | Manufacturer | Function |
|---------------|----------|-------------|-------------------|------------------------|
| C1 (optional) | 1nF | 0402 | Various | DC block ¹ |
| C2 (optional) | ≥ 1nF | 0402 | Various | RF bypass ² |
| L1 | 16nH | 0402 | Murata LQW15 type | Input matching |
| N1 | BGA125N6 | PG-TSNP-6-2 | Infineon | GNSS LNA |

¹DC block might be realized with pre-filter in GNSS applications.

²RF bypass recommended to mitigate power supply noise.



Package Information

5 Package Information

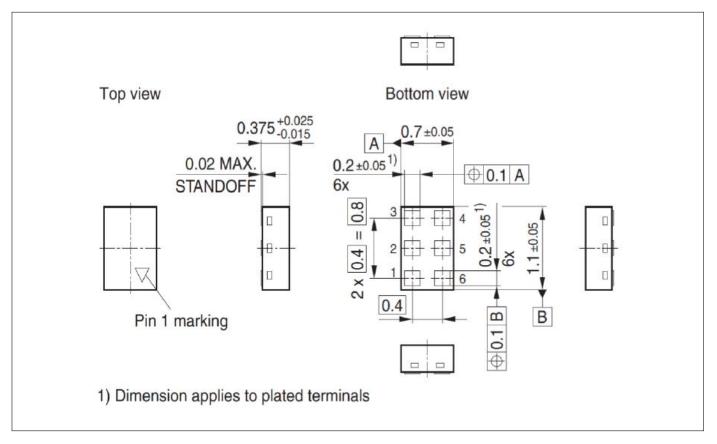


Figure 4: PG-TSNP-6-2 Package Outline (0.7mm x 1.1mm x 0.375mm)

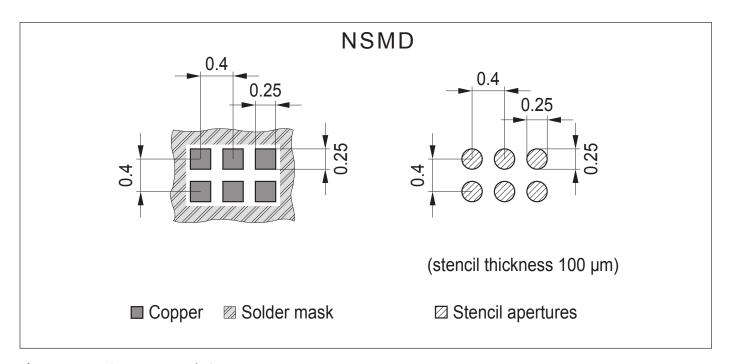


Figure 5: Footprint Recommendation

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Package Information

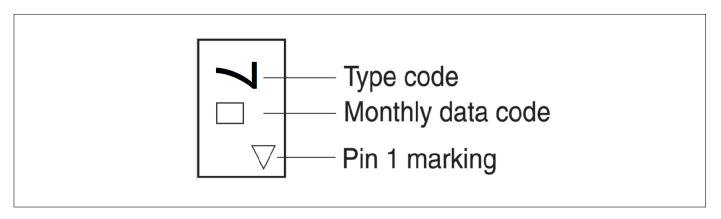


Figure 6: Marking Specification (top view)

Table 8: Monthly Date Code Marking

| Month | 2015 | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 |
|-------|------|------|------|------|------|------|------|------|------|------|------|------|
| 1 | а | р | Α | Р | а | р | Α | Р | а | р | Α | Р |
| 2 | b | q | В | Q | b | q | В | Q | b | q | В | Q |
| 3 | С | r | С | R | С | r | С | R | С | r | С | R |
| 4 | d | S | D | S | d | S | D | S | d | s | D | S |
| 5 | е | t | Е | Т | е | t | E | Т | е | t | E | Т |
| 6 | f | u | F | U | f | u | F | U | f | u | F | U |
| 7 | g | V | G | V | g | v | G | V | g | v | G | V |
| 8 | h | х | Н | Х | h | x | Н | Х | h | x | Н | X |
| 9 | j | у | J | Υ | j | у | J | Υ | j | у | J | Y |
| 10 | k | z | K | Z | k | z | K | Z | k | z | K | Z |
| 11 | l | 2 | L | 4 | l | 2 | L | 4 | l | 2 | L | 4 |
| 12 | n | 3 | N | 5 | n | 3 | N | 5 | n | 3 | N | 5 |

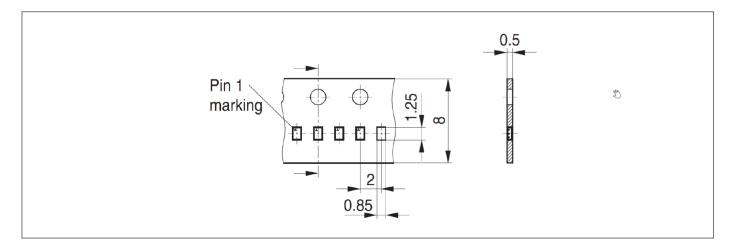


Figure 7: PG-TSNP-6-2 Carrier Tape





| Revision History | |
|-------------------------|--|
| - | |
| Page or Item | Subjects (major changes since previous revision) |
| Revision 2.1, 202 | I-02-22 |
| Revision History | |
| 7 | Figure 2 changed to top view |
| | |
| | |
| | |

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